74LVCH32245A

32-bit bus transceiver with direction pin; 5 V tolerant; 3-state

Rev. 03 — 20 August 2007

Product data sheet

1. General description

The 74LVCH32245A is a 32-bit transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions. The device features four output enable $(n\overline{OE})$ inputs for easy cascading and four send/receive (nDIR) inputs for direction control. Pin $n\overline{OE}$ controls the outputs so that the buses are effectively isolated.

Inputs can be driven from either 3.3 V or 5 V devices. When disabled, up to 5.5 V can be applied to the outputs. These features allow the use of these devices in mixed 3.3 V and 5 V applications.

To ensure the high-impedance state during power-up or power-down, pin $n\overline{OE}$ should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Bus hold on data inputs eliminates the need for external pull-up resistors to hold unused inputs.

2. Features

- 5 V tolerant inputs/outputs for interfacing with 5 V logic
- Wide supply voltage range from 1.2 V to 3.6 V
- CMOS low power consumption
- MULTIBYTE flow-through standard pin-out architecture
- Low inductance multiple power and ground pins for minimum noise and ground bounce
- Direct interface with TTL levels
- Inputs accept voltages up to 5.5 V
- High-impedance when $V_{CC} = 0 \text{ V}$
- All data inputs have bus hold
- Complies with JEDEC standard JESD8-B / JESD36
- ESD protection:
 - ◆ HBM EIA/JESD22-A114-B exceeds 2000 V
 - MM EIA/JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C
- Packaged in plastic fine-pitch ball grid array package



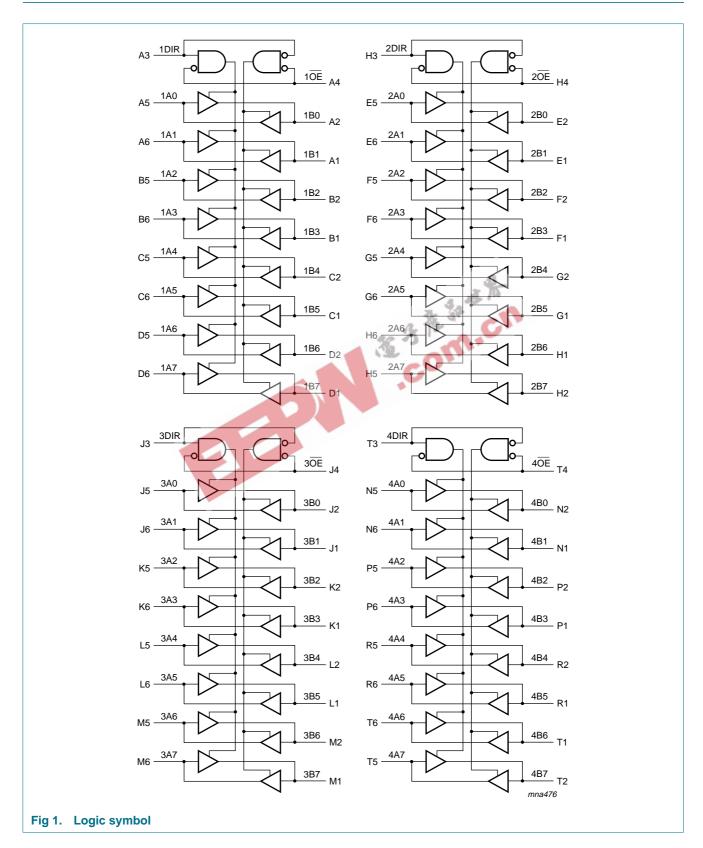
3. Ordering information

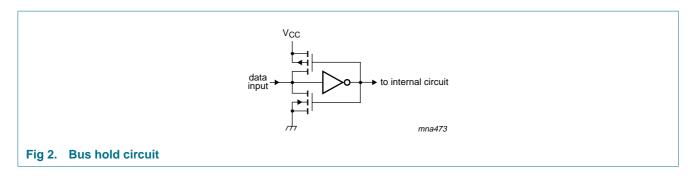
Table 1. Ordering information

Type number	Package				
	Temperature range	Name	Description	Version	
74LVCH32245AEC	–40 °C to +85 °C	LFBGA96	plastic low profile fine-pitch ball grid array package; 96 balls; body $13.5 \times 5.5 \times 1.05$ mm	SOT536-1	



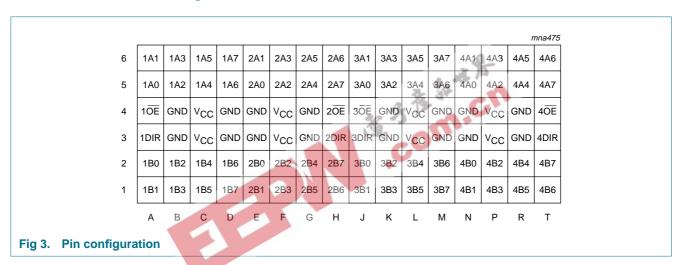
4. Functional diagram





5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Pin name	Ball	Description
nDIR (n = 1 to 4)	A3, H3, J3, T3	direction control
$n\overline{OE}$ (n = 1 to 4)	A4, H4, J4, T4	output enable input (active LOW)
1A[0:7]	A5, A6, B5, B6, C5, C6, D5, D6	input or output
1B[0:7]	A2, A1, B2, B1, C2, C1, D2, D1	input or output
2A[0:7]	E5, E6, F5, F6, G5, G6, H6, H5	input or output
2B[0:7]	E2, E1, F2, F1, G2, G1, H1, H2	input or output
3A[0:7]	J5, J6, K5, K6, L5, L6, M5, M6	input or output
3B[0:7]	J2, J1, K2, K1, L2, L1, M2, M1	input or output
4A[0:7]	N5, N6, P5, P6, R5, R6, T6, T5	input or output
4B[0:7]	N2, N1, P2, P1, R2, R1, T1, T2	input or output
GND	B3, B4, D3, D4, E3, E4, G3, G4, K3, K4, M3, M4, N3, N4, R3, R4	ground (0 V)
Vcc	C3, C4, F3, F4, L3, L4, P3, P4	supply voltage

6. Functional description

Table 3. Function selection^[1]

		Output		
nOE	nDIR	nAn	nBn	
L	L	A = B	inputs	
L	Н	inputs	B = A	
Н	X	Z	Z	

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+6.5	V
I_{IK}	input clamping current	V _I < 0 V	-50	-	mA
V_{I}	input voltage	Va > Va or Va < 0 V	<u>[1]</u> -0.5	+6.5	V
I _{OK}	output clamping current	$V_O > V_{CC}$ or $V_O < 0 V$	11.	±50	mA
V _O	output voltage	output HIGH or LOW state	<u>[2]</u> −0.5	$V_{CC} + 0.5$	V
		output 3-state	<u>[2]</u> –0.5	+6.5	V
I _O	output current	$V_O = 0 \text{ V to } V_{CC}$	-	±50	mA
I _{CC}	supply current		[3] _	200	mA
I_{GND}	ground current		<u>[3]</u> −200	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}$	[4] _	1000	mW

^[1] The minimum input voltage ratings may be exceeded if the input current ratings are observed.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage	for maximum speed performance	2.7	-	3.6	V
	for low-voltage applications	1.2	-	-	V	
VI	input voltage		0	-	5.5	V
Vo	output voltage	output HIGH or LOW state	0	-	V_{CC}	V
		output 3-state	0	-	5.5	V
T _{amb}	ambient temperature	in free air	-40	-	+85	°C
Δt/ΔV input transition rate	input transition rise and fall	$V_{CC} = 1.2 \text{ V to } 2.7 \text{ V}$	-	-	20	ns/V
	rate	V _{CC} = 2.7 V to 3.6 V	-	-	10	ns/V

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^[2] The output voltage ratings may be exceeded if the output current ratings are observed.

^[3] All supply and ground pins connected externally to one voltage source.

^[4] Above 70 $^{\circ}$ C the value of P_{tot} derates linearly with 1.8 mW/K.

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	V _{CC} (V)		Min	Typ[1]	Max	Unit
$T_{amb} = -4$	40 °C to +85 °C							
V_{IH}	HIGH-level input voltage		1.2		V_{CC}	-	-	V
			2.7 to 3.6		2.0	-	-	V
V _{IL}	LOW-level input voltage		1.2		-	-	GND	V
			2.7 to 3.6		-	-	8.0	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}						
		$I_{O} = -100 \ \mu A$	2.7 to 3.6		$V_{CC}-0.2$	V_{CC}	-	V
		$I_O = -12 \text{ mA}$	2.7		$V_{CC}-0.5$	-	-	V
		$I_{O} = -18 \text{ mA}$	3.0		$V_{CC}-0.6$	-	-	V
		$I_O = -24 \text{ mA}$	3.0		$V_{CC} - 0.8$	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}		_ <	2-			
		$I_{O} = 100 \mu A$	2.7 to 3.6	18)10 -	GND	0.20	V
		I _O = 12 mA	2.7 3.0	-	11.	-	0.40	V
		I _O = 24 mA	3.0	400	-	-	0.55	V
I _I	input leakage current	V _I = 5.5 V or GND	3.6	[2]	-	±0.1	±5	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = 5.5$ V or GND	3.6	[2][3]	-	±0.1	±5	μΑ
I _{OFF}	power-off leakage current	V_I or $V_O = 5.5 \text{ V}$	0.0		-	±0.1	±10	μΑ
Icc	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A	3.6		-	0.1	40	μΑ
ΔI_{CC}	additional supply current	per input pin; $V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}$	2.7 to 3.6		-	5	500	μΑ
Cı	input capacitance	$V_I = GND$ to V_{CC}	0 to 3.6		-	5.0	-	pF
C _{I/O}	input/output capacitance	$V_I = GND$ to V_{CC}	0 to 3.6		-	10	-	pF
I _{BHL}	bus hold LOW current	$V_{I} = 0.8 \text{ V}$	3.0	[4][5]	75	-	-	μΑ
I _{BHH}	bus hold HIGH current	V _I = 2.0 V	3.0	[4][5]	-75	-	-	μΑ
I _{BHLO}	bus hold LOW overdrive current		3.6	[4][6]	500	-	-	μΑ
I _{BHHO}	bus hold HIGH overdrive current		3.6	[4][6]	-500	-	-	μΑ

^[1] All typical values are measured at V_{CC} = 3.3 V (unless stated otherwise) and T_{amb} = 25 °C.

^[2] The bus hold circuit is switched off when V_{l} > V_{CC} allowing 5.5 V on the input terminal.

^[3] For I/O ports the parameter I_{OZ} includes the input leakage current.

^[4] Valid for data inputs only. Note that control inputs do not have a bus hold circuit.

^[5] The specified sustaining current at the data input holds the input below the specified $V_{\rm I}$ level.

^[6] The specified overdrive current at the data input forces the data input to the opposite input state.

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10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 6.

Symbol	Parameter	Conditions	V _{CC} (V)		Min	Typ[1]	Max	Unit
T _{amb} = -4	40 °C to +85 °C							
t _{pd}	propagation delay	nAn to nBn; nBn to nAn; see	1.2	[2]	-	13.0	-	ns
	Figure 4	2.7		1.0	2.7	4.7	ns	
			3.0 to 3.6		1.0	2.2	4.5	ns
t _{en}	enable time	nOE to nAn, nBn: see Figure 5	1.2	[2]	-	15.0	-	ns
			2.7		1.5	3.6	6.7	ns
		3.0 to 3.6		1.0	2.8	5.5	ns	
t _{dis}	disable time	nOE to nAn, nBn; see Figure 5	1.2	[2]	-	11.0	-	ns
			2.7		1.5	3.4	6.6	ns
			3.0 to 3.6		1.5	3.2	5.6	ns
t _{sk(o)}	output skew time		3.0 to 3.6	<u>[3]</u>	-	-	1.0	ns
C_{PD}	power dissipation capacitance	per buffer; $V_I = GND$ to V_{CC}	3.3	<u>[4]</u>	0	30	-	pF

- [1] Typical values are measured at $T_{amb} = 25$ °C and $V_{CC} = 1.2$ V, 2.7 V, and 3.3 V respectively.
- [2] t_{pd} is the same as t_{PLH} and t_{PHL} . t_{en} is the same as t_{PZL} and t_{PZH} .
 - $t_{\mbox{\scriptsize dis}}$ is the same as $t_{\mbox{\scriptsize PLZ}}$ and $t_{\mbox{\scriptsize PHZ}}.$
- [3] Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.
- [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz; f_o = output frequency in MHz

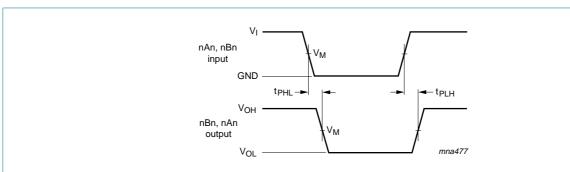
C_L = output load capacitance in pF

V_{CC} = supply voltage in Volts

N = number of inputs switching

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

11. Waveforms



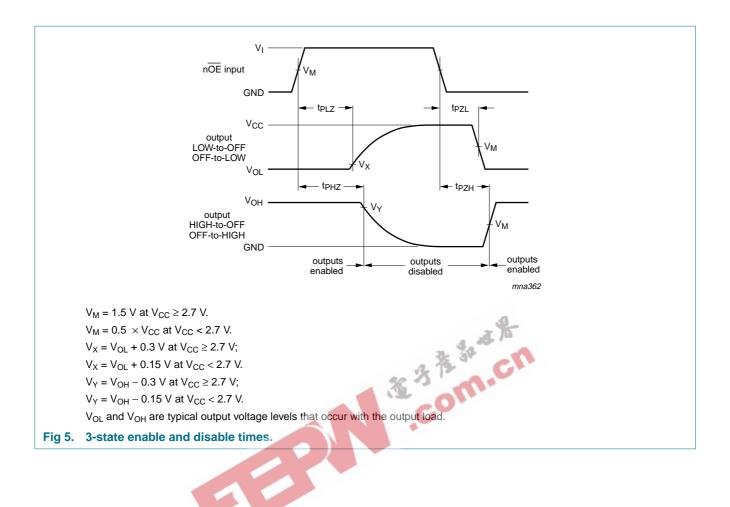
 V_M = 1.5 V at $V_{CC} \geq$ 2.7 V.

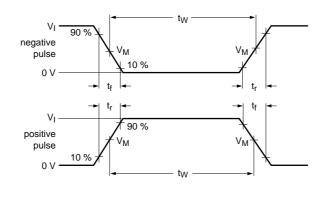
 $V_M = 0.5 \times V_{CC}$ at $V_{CC} < 2.7$ V.

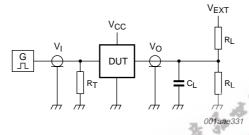
 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 4. The input (nAn, nBn) to output (nBn, nAn) propagation delays

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Test data is given in Table 8.

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig 6. Load circuitry for switching times

Table 8. Test data

Supply voltage	Input		Load		V _{EXT}		
	VI	t _r , t _f	CL	R _L	t _{PLH} , t _{PHL}	t_{PLZ}, t_{PZL}	t _{PHZ} , t _{PZH}
1.2 V	V _{CC}	≤ 2 ns	50 pF	500Ω	open	$2\times V_{\text{CC}}$	GND
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500Ω	open	$2 \times V_{CC}$	GND
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500Ω	open	$2 \times V_{CC}$	GND

12. Package outline

LFBGA96: plastic low profile fine-pitch ball grid array package; 96 balls; body 13.5 x 5.5 x 1.05 mm SOT536-1

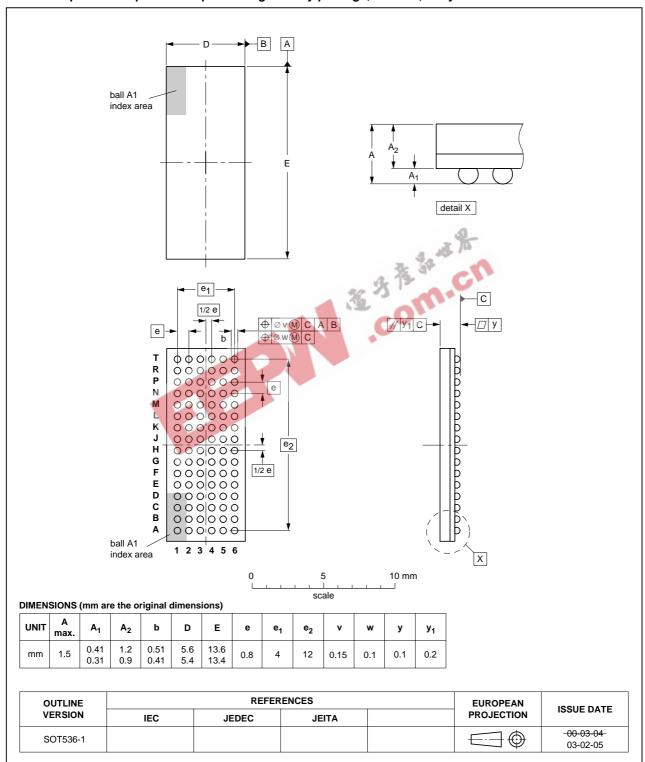


Fig 7. Package outline SOT536-1 (LFBGA96)

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13. Abbreviations

Table 9. Abbreviations

Acronym	Description
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVCH32245A_3	20070820	Product data sheet	-	74LVCH32245A_2
Modifications:		his data sheet has been IXP Semiconductors.	redesigned to compl	y with the new identity
	 Legal texts have 	ve been adapted to the no	ew company na <mark>me w</mark>	here appropriate.
	 Error in <u>Table 2</u> 	2 "Pin description" correc	ted.	
	 Quick Reference and <u>Table 7</u>. 	ce Data secti <mark>on</mark> deleted. I	nformation (C _{PD} , C _I ,	C _{I/O}) moved from it to <u>Table 6</u>
	 Some paramet guidelines. 	ter symbols and descripti	ons have been upda	ted to comply with NXP
74LVCH32245A_2	20040511	Product specification	-	74LVC_LVCH32245A_1
74LVC_LVCH32245A_1	19990901		-	-
-				

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15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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